

# Switching (600V, 7A)

## 2SK2740

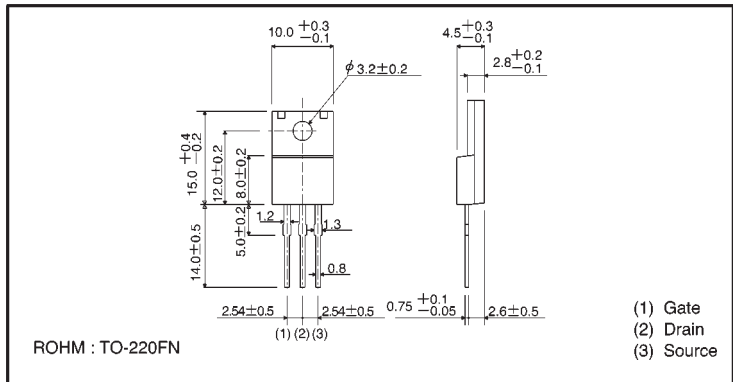
### ●Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Wide SOA (safe operating area).
- 4) Gate-source voltage ( $V_{GS}$ ) guaranteed to be  $\pm 30V$ .
- 5) Easily designed drive circuits.
- 6) Easy to parallel.

### ●Structure

Silicon N-channel  
MOSFET

### ●External dimensions (Units: mm)



### ●Absolute maximum ratings ( $T_a = 25^\circ C$ )

Parameter		Symbol	Limits	Unit
Drain-source voltage		$V_{DSS}$	600	V
Gate-source voltage		$V_{GSS}$	$\pm 30$	V
Drain current	Continuous	$I_D$	7	A
	Pulsed	$I_{DP}^*$	28	A
Reverse drain current	Continuous	$I_{DR}$	7	A
	Pulsed	$I_{DRP}^*$	28	A
Total power dissipation ( $T_c=25^\circ C$ )		$P_D$	30	W
Channel temperature		$T_{ch}$	150	$^\circ C$
Storage temperature		$T_{stg}$	$-55 \sim +150$	$^\circ C$

\*  $P_W \leq 10 \mu s$ , Duty cycle  $\leq 1\%$

### ●Packaging specifications

Type	Package	Bulk
	Code	—
	Basic ordering unit (pieces)	500
2SK2740		○

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Gate-source leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> =±30V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	600	—	—	V	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	—	—	100	μA	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS(th)</sub>	2.0	—	4.0	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
Static drain-source on-state resistance	R <sub>DS(on)</sub>	—	1.0	1.2	Ω	I <sub>D</sub> =4A, V <sub>GS</sub> =10V
Forward transfer admittance	Y <sub>fs</sub>  *	3.0	6.0	—	S	I <sub>D</sub> =4A, V <sub>DS</sub> =10V
Input capacitance	C <sub>iss</sub>	—	1050	—	pF	V <sub>DS</sub> =10V
Output capacitance	C <sub>oss</sub>	—	210	—	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	—	80	—	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub>	—	19	—	ns	I <sub>D</sub> =4A, V <sub>DD</sub> ≐150V
Rise time	t <sub>r</sub>	—	22	—	ns	V <sub>GS</sub> =10V
Turn-off delay time	t <sub>d(off)</sub>	—	79	—	ns	R <sub>L</sub> =37.5Ω
Fall time	t <sub>f</sub>	—	30	—	ns	R <sub>G</sub> =10Ω
Reverse recovery time	t <sub>rr</sub>	—	590	—	ns	I <sub>DR</sub> =7A, V <sub>GS</sub> =0V
Reverse recovery charge	Q <sub>rr</sub>	—	4.6	—	μC	di/dt=100A/μs

\* Pw≦300 μs, Duty cycle≦1%

●Electrical characteristic curves

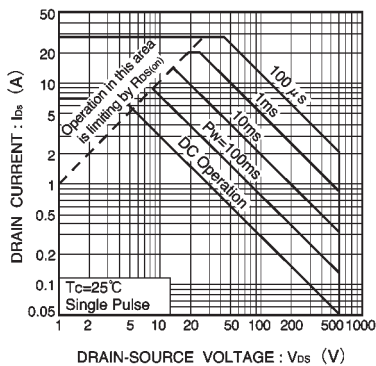


Fig.1 Maximum safe operating area

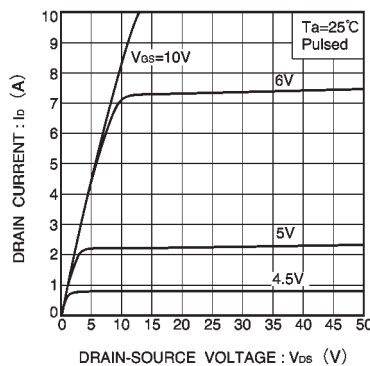


Fig.2 Typical output characteristics

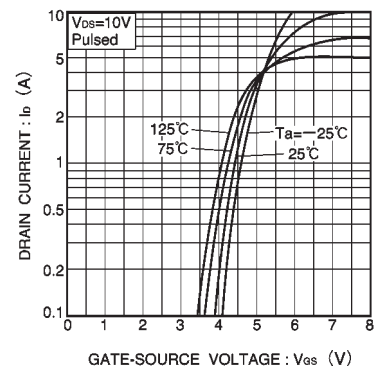


Fig.3 Typical transfer characteristics

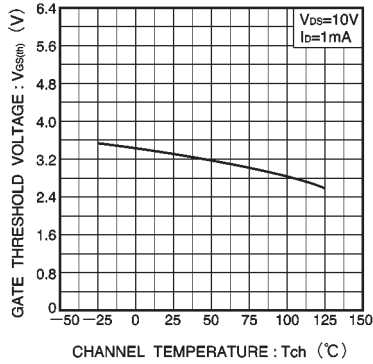


Fig.4 Gate threshold voltage vs. channel temperature

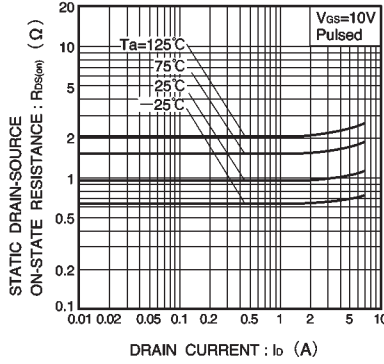


Fig.5 Static drain-source on-state resistance vs. drain current

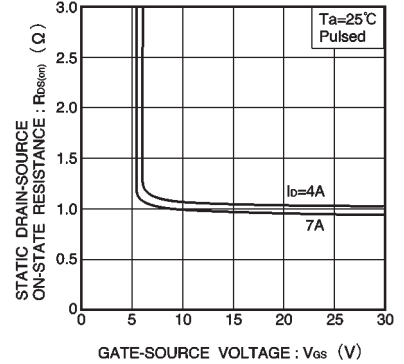


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

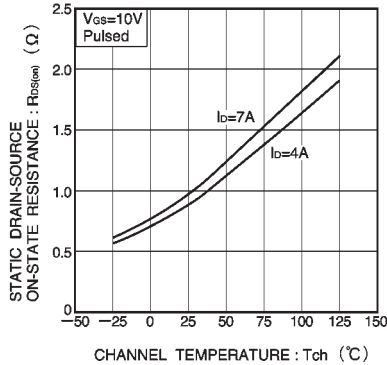


Fig.7 Static drain-source on-state resistance vs. channel temperature

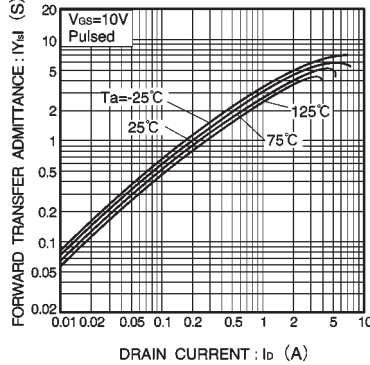


Fig.8 Forward transfer admittance vs. drain current

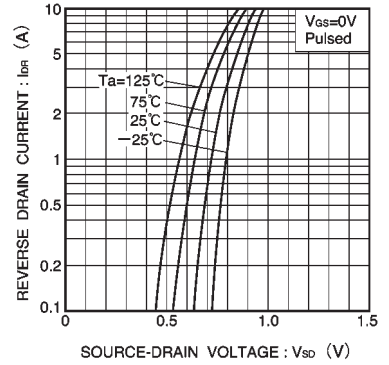


Fig.9 Reverse drain current vs. source-drain voltage ( I )

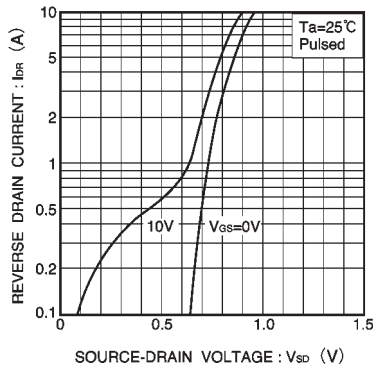


Fig.10 Reverse drain current vs. source-drain voltage ( II )

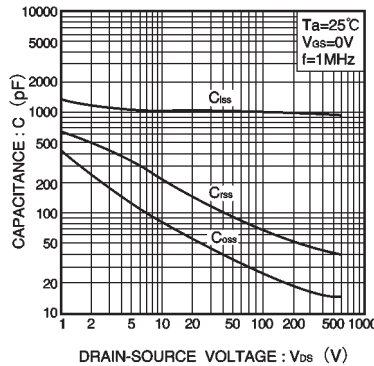


Fig.11 Typical capacitance vs. drain-source voltage

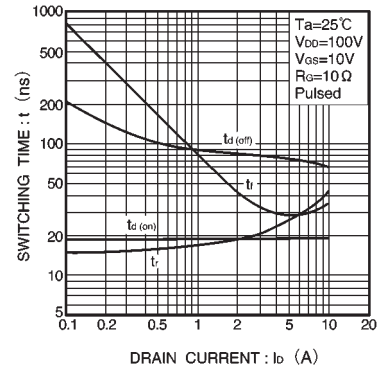


Fig.12 Switching characteristics ( See Figures 16 and 17 for the measurement circuit and resultant waveforms )

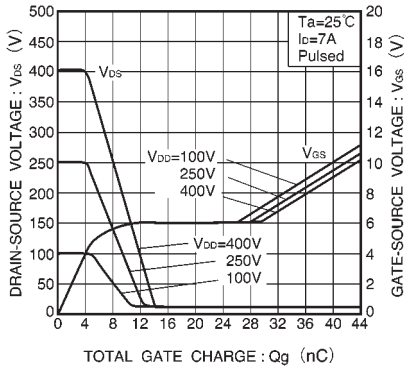


Fig.13 Dynamic input characteristics  
(See Figure 18 for measurement circuit)

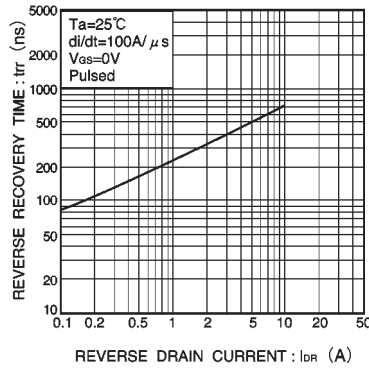


Fig.14 Reverse recovery time vs. reverse drain current

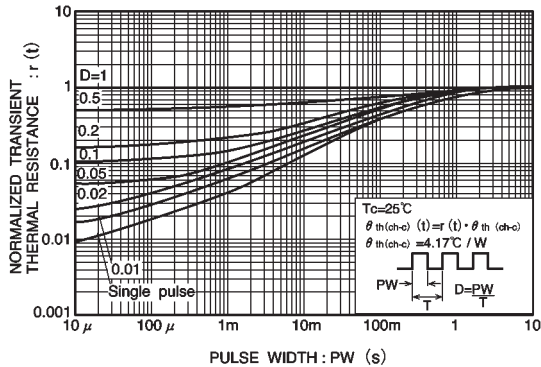


Fig.15 Normalized transient thermal resistance vs. pulse width

● Switching characteristics measurement circuit

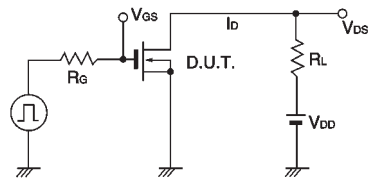


Fig.16 Switching time measurement circuit

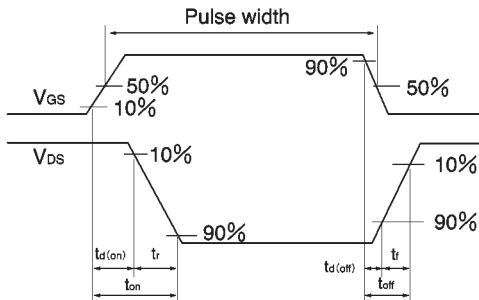


Fig.17 Switching time waveforms

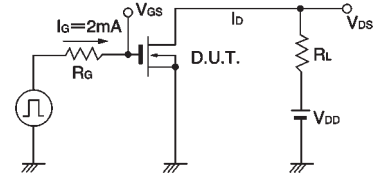


Fig.18 Gate charge measurement circuit

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